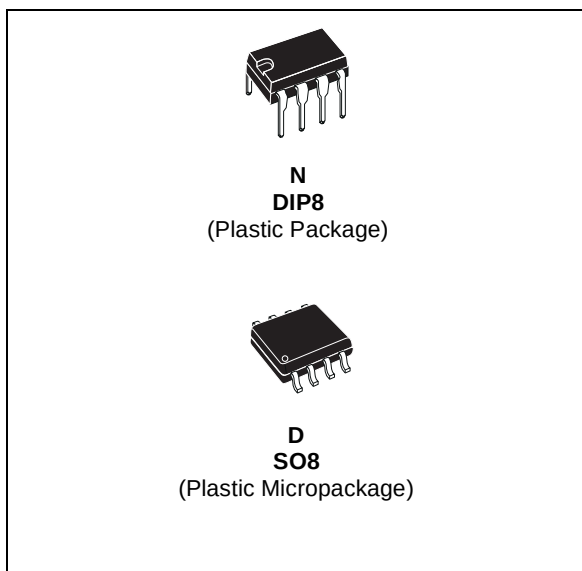


## WIDE BANDWIDTH SINGLE J-FET OPERATIONAL AMPLIFIER

- INTERNALLY ADJUSTABLE INPUT OFFSET VOLTAGE
- LOW POWER CONSUMPTION
- WIDE COMMON-MODE (UP TO  $V_{CC}^+$ ) AND DIFFERENTIAL VOLTAGE RANGE
- LOW INPUT BIAS AND OFFSET CURRENT
- OUTPUT SHORT-CIRCUIT PROTECTION
- HIGH INPUT IMPEDANCE J-FET INPUT STAGE
- INTERNAL FREQUENCY COMPENSATION
- LATCH UP FREE OPERATION
- HIGH SLEW RATE : 16V/ $\mu$ s (typ)

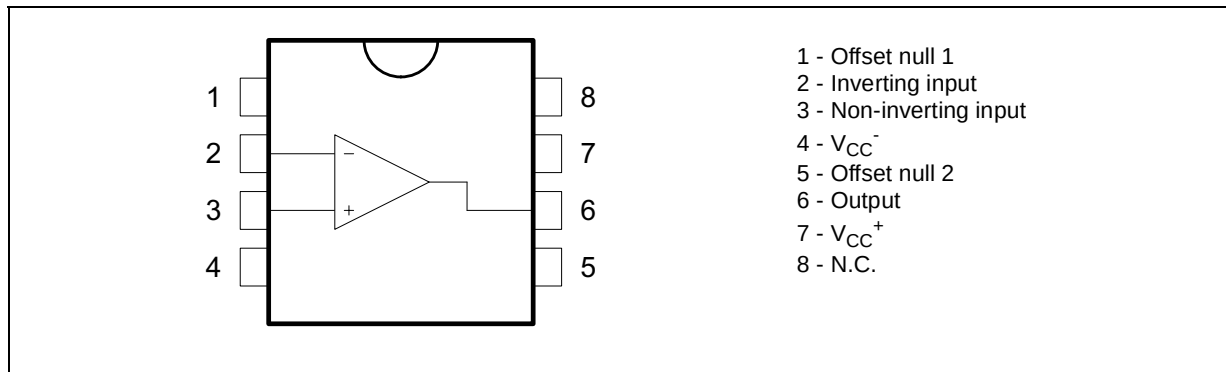


### DESCRIPTION

These circuits are high speed J-FET input single-operational amplifiers incorporating well matched, high voltage J-FET and bipolar transistors in a monolithic integrated circuit.

The devices feature high slew rates, low input bias and offset currents, and low offset voltage temperature coefficient.

### PIN CONNECTIONS (top view)

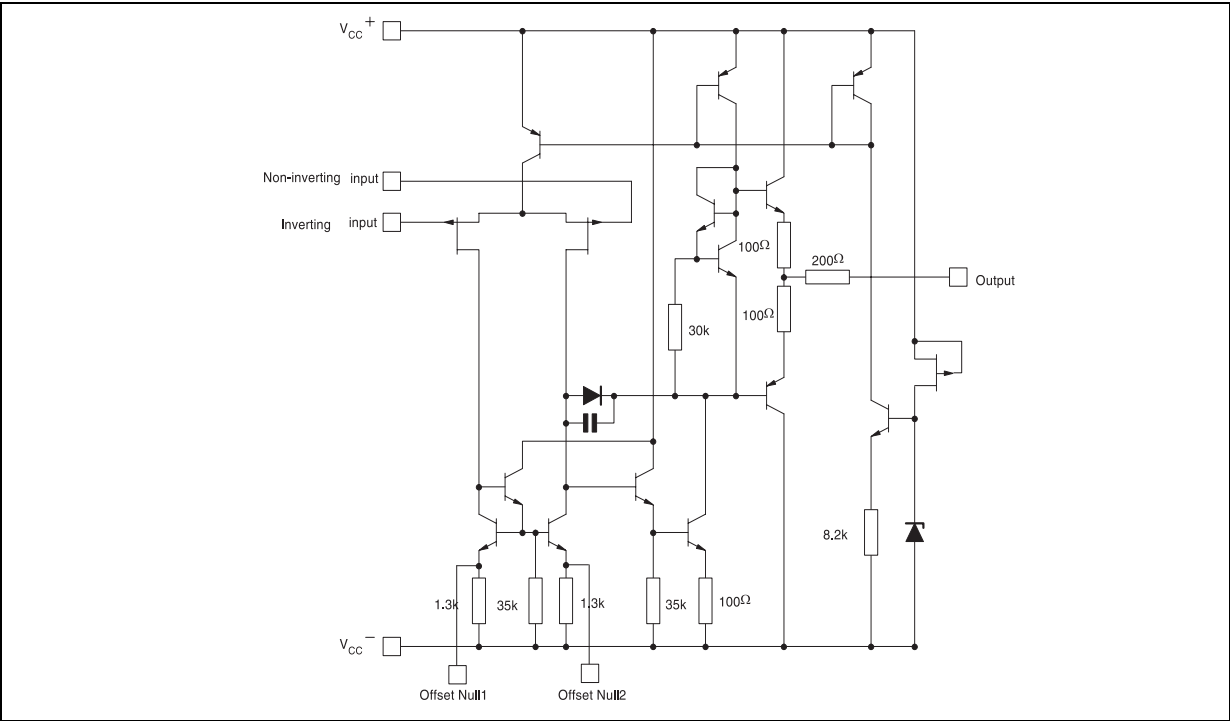


### ORDER CODE

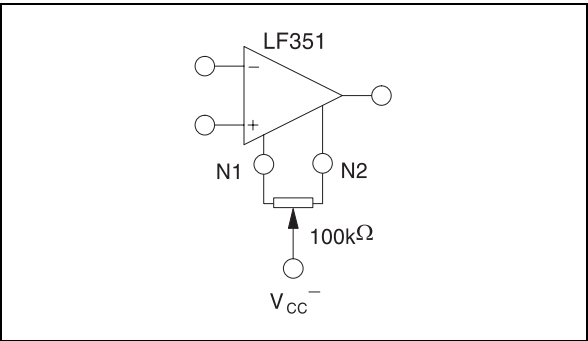
| Part Number | Temperature Range | Package |   |
|-------------|-------------------|---------|---|
|             |                   | N       | D |
| LF351       | 0°C, +70°C        | •       | • |
| LF251       | -40°C, +105°C     | •       | • |
| LF151       | -55°C, +125°C     | •       | • |

**N** = Dual in Line Package (DIP)  
**D** = Small Outline Package (SO) - also available in Tape & Reel (DT)

SCHEMATIC DIAGRAM



INPUT OFFSET VOLTAGE NULL CIRCUIT



ABSOLUTE MAXIMUM RATINGS

| Symbol     | Parameter                                          | LF151       | LF251       | LF351    | Unit |
|------------|----------------------------------------------------|-------------|-------------|----------|------|
| $V_{CC}$   | Supply voltage - note <sup>1)</sup>                | $\pm 18$    |             |          | V    |
| $V_i$      | Input Voltage - note <sup>2)</sup>                 | $\pm 15$    |             |          | V    |
| $V_{id}$   | Differential Input Voltage - note <sup>3)</sup>    | $\pm 30$    |             |          | V    |
| $P_{tot}$  | Power Dissipation                                  | 680         |             |          | mW   |
|            | Output Short-circuit Duration - note <sup>4)</sup> | Infinite    |             |          |      |
| $T_{oper}$ | Operating Free-air Temperature Range               | -55 to +125 | -40 to +105 | 0 to +70 | °C   |
| $T_{stg}$  | Storage Temperature Range                          | -65 to +150 |             |          | °C   |

1. All voltage values, except differential voltage, are with respect to the zero reference level (ground) of the supply voltages where the zero reference level is the midpoint between  $V_{CC}^+$  and  $V_{CC}^-$ .
2. The magnitude of the input voltage must never exceed the magnitude of the supply voltage or 15 volts, whichever is less.
3. Differential voltages are the non-inverting input terminal with respect to the inverting input terminal.
4. The output may be shorted to ground or to either supply. Temperature and/or supply voltages must be limited to ensure that the dissipation rating is not exceeded

# ELECTRICAL CHARACTERISTICS

$V_{CC} = \pm 15V$ ,  $T_{amb} = +25^{\circ}C$  (unless otherwise specified)

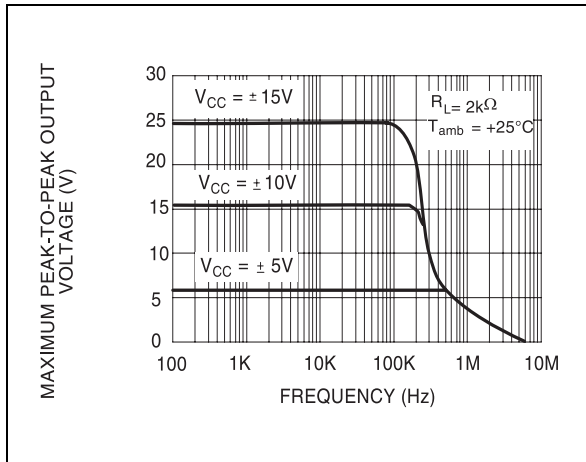
| Symbol        | Parameter                                                                                                                                                                 | Min.                 | Typ.       | Max.       | Unit                   |
|---------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------|----------------------|------------|------------|------------------------|
| $V_{io}$      | Input Offset Voltage ( $R_S = 10k\Omega$ )<br>$T_{amb} = +25^{\circ}C$<br>$T_{min} \leq T_{amb} \leq T_{max}$                                                             |                      | 3          | 10<br>13   | mV                     |
| $DV_{io}$     | Input Offset Voltage Drift                                                                                                                                                |                      | 10         |            | $\mu V/^{\circ}C$      |
| $I_{io}$      | Input Offset Current- note 1)<br>$T_{amb} = +25^{\circ}C$<br>$T_{min} \leq T_{amb} \leq T_{max}$                                                                          |                      | 5          | 100<br>4   | pA<br>nA               |
| $I_{ib}$      | Input Bias Current -note 1<br>$T_{amb} = +25^{\circ}C$<br>$T_{min} \leq T_{amb} \leq T_{max}$                                                                             |                      | 20         | 200<br>20  | nA                     |
| $A_{vd}$      | Large Signal Voltage Gain ( $R_L = 2k\Omega$ , $V_o = \pm 10V$ )<br>$T_{amb} = +25^{\circ}C$<br>$T_{min} \leq T_{amb} \leq T_{max}$                                       | 50<br>25             | 200        |            | V/mV                   |
| SVR           | Supply Voltage Rejection Ratio ( $R_S = 10k\Omega$ )<br>$T_{amb} = +25^{\circ}C$<br>$T_{min} \leq T_{amb} \leq T_{max}$                                                   | 80<br>80             | 86         |            | dB                     |
| $I_{CC}$      | Supply Current, no load<br>$T_{amb} = +25^{\circ}C$<br>$T_{min} \leq T_{amb} \leq T_{max}$                                                                                |                      | 1.4        | 3.4<br>3.4 | mA                     |
| $V_{icm}$     | Input Common Mode Voltage Range                                                                                                                                           | $\pm 11$             | +15<br>-12 |            | V                      |
| CMR           | Common Mode Rejection Ratio ( $R_S = 10k\Omega$ )<br>$T_{amb} = +25^{\circ}C$<br>$T_{min} \leq T_{amb} \leq T_{max}$                                                      | 70<br>70             | 86         |            | dB                     |
| $I_{OS}$      | Output Short-circuit Current<br>$T_{amb} = +25^{\circ}C$<br>$T_{min} \leq T_{amb} \leq T_{max}$                                                                           | 10<br>10             | 40         | 60<br>60   | mA                     |
| $\pm V_{opp}$ | Output Voltage Swing<br>$T_{amb} = +25^{\circ}C$<br>$T_{min} \leq T_{amb} \leq T_{max}$<br>$R_L = 2k\Omega$<br>$R_L = 10k\Omega$<br>$R_L = 2k\Omega$<br>$R_L = 10k\Omega$ | 10<br>12<br>10<br>12 | 12<br>13.5 |            | V                      |
| SR            | Slew Rate<br>$V_i = 10V$ , $R_L = 2k\Omega$ , $C_L = 100pF$ , $T_{amb} = +25^{\circ}C$ , unity gain                                                                       | 12                   | 16         |            | V/ $\mu s$             |
| $t_r$         | Rise Time<br>$V_i = 20mV$ , $R_L = 2k\Omega$ , $C_L = 100pF$ , $T_{amb} = +25^{\circ}C$ , unity gain                                                                      |                      | 0.1        |            | $\mu s$                |
| $K_{ov}$      | Overshoot<br>$V_i = 20mV$ , $R_L = 2k\Omega$ , $C_L = 100pF$ , $T_{amb} = +25^{\circ}C$ , unity gain                                                                      |                      | 10         |            | %                      |
| GBP           | Gain Bandwidth Product<br>$f = 100kHz$ , $T_{amb} = +25^{\circ}C$ , $V_{in} = 10mV$ , $R_L = 2k\Omega$ , $C_L = 100pF$                                                    | 2.5                  | 4          |            | MHz                    |
| $R_i$         | Input Resistance                                                                                                                                                          |                      | $10^{12}$  |            | $\Omega$               |
| THD           | Total Harmonic Distortion ( $f = 1kHz$ , $A_v = 20dB$<br>$R_L = 2k\Omega$ , $C_L = 100pF$ , $T_{amb} = +25^{\circ}C$ , $V_o = 2V_{pp}$ )                                  |                      | 0.01       |            |                        |
| $e_n$         | Equivalent Input Noise Voltage<br>$R_S = 100\Omega$ , $f = 1KHz$                                                                                                          |                      | 15         |            | $\frac{nV}{\sqrt{Hz}}$ |
| $\phi_m$      | Phase Margin                                                                                                                                                              |                      | 45         |            | Degrees                |

1. The input bias currents are junction leakage currents which approximately double for every  $10^{\circ}C$  increase in the junction temperature.

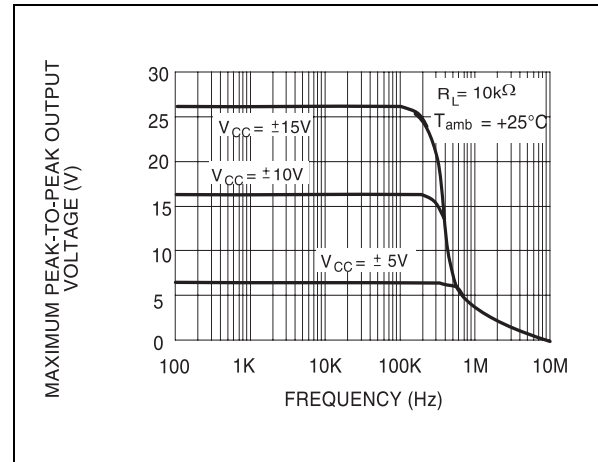
## MAXIMUM PEAK-TO-PEAK OUTPUT



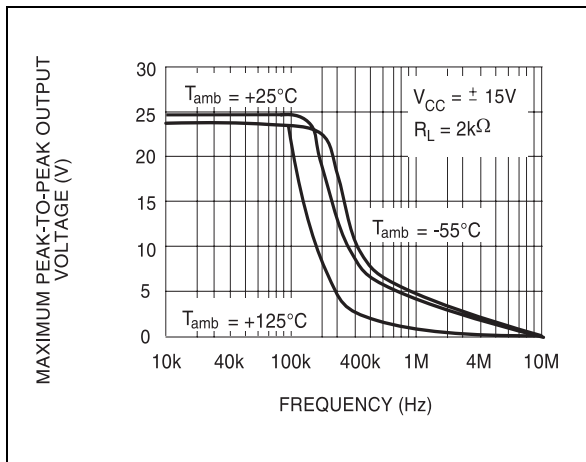
**VOLTAGE versus FREQUENCY**



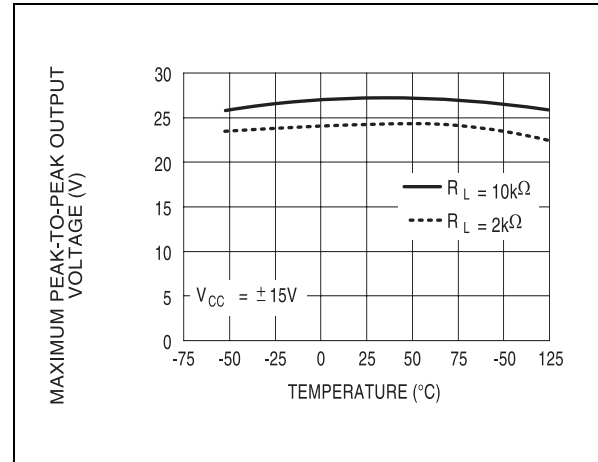
**VOLTAGE versus FREQUENCY**



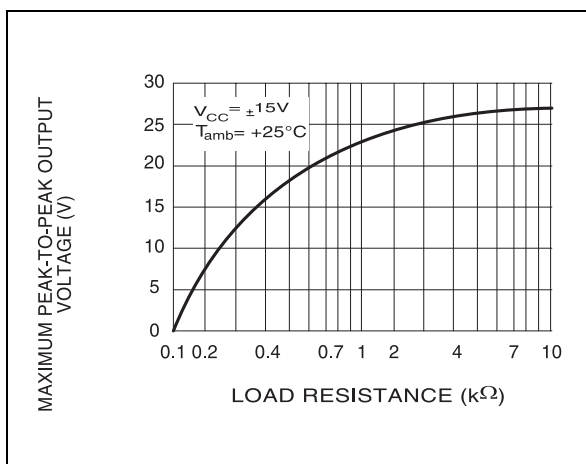
**MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE versus FREQUENCY**



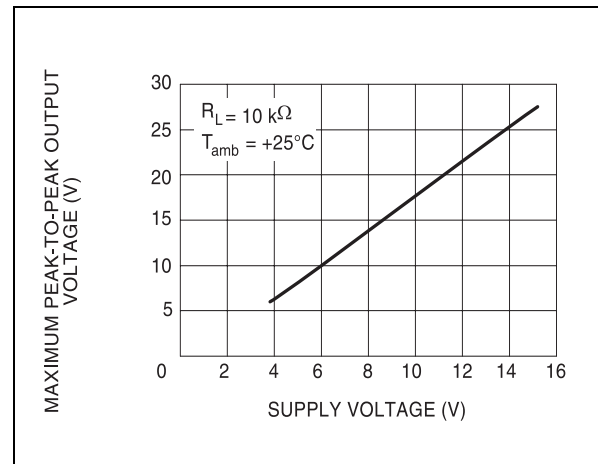
**MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE versus FREE AIR TEMP.**



**MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE versus LOAD RESISTANCE**



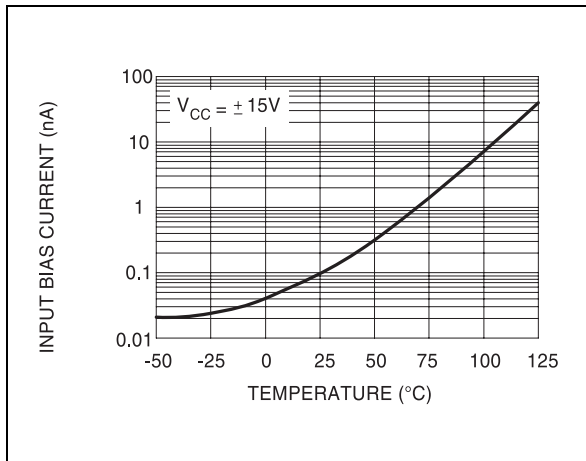
**MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE versus SUPPLY VOLTAGE**



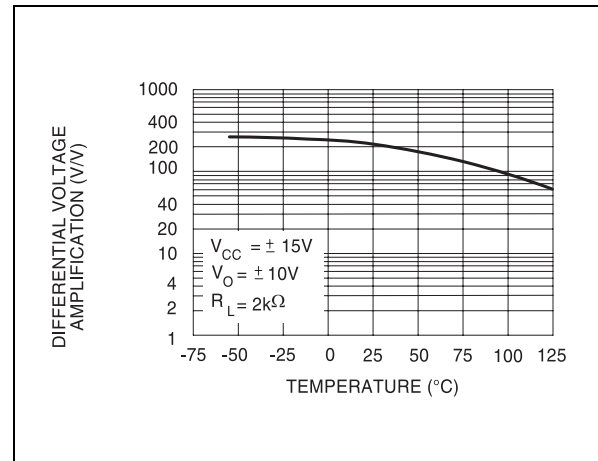
**MAXIMUM PEAK-TO-PEAK OUTPUT**

**INPUT BIAS CURRENT versus FREE AIR**

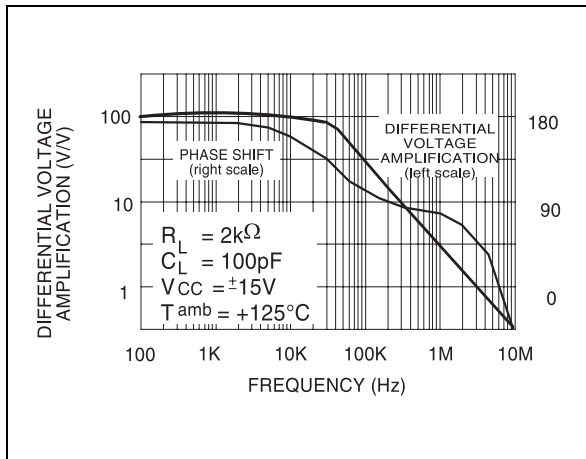
## TEMPERATURE



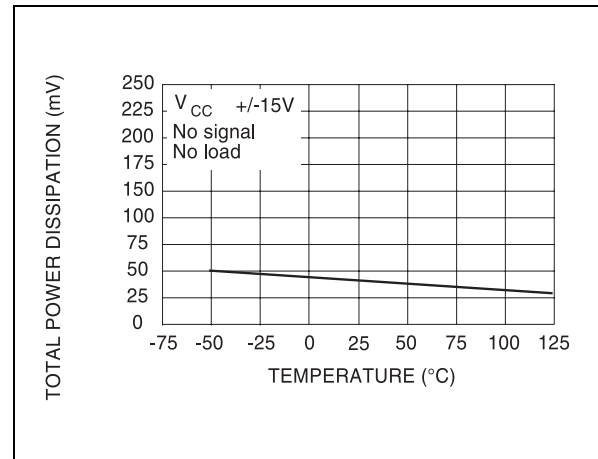
## AMPLIFICATION versus FREE AIR TEMP.



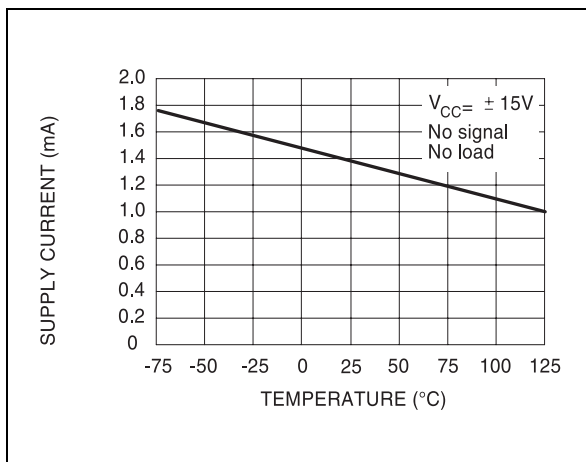
## LARGE SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE SHIFT versus FREQUENCY



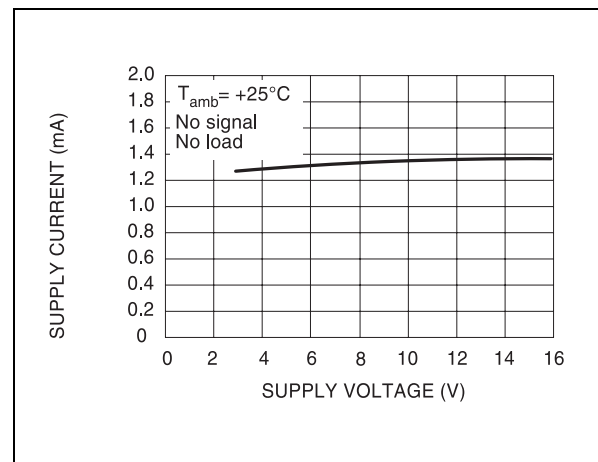
## TOTAL POWER DISSIPATION versus FREE AIR TEMPERATURE



## SUPPLY CURRENT PER AMPLIFIER versus FREE AIR TEMPERATURE



## SUPPLY CURRENT PER AMPLIFIER versus SUPPLY VOLTAGE

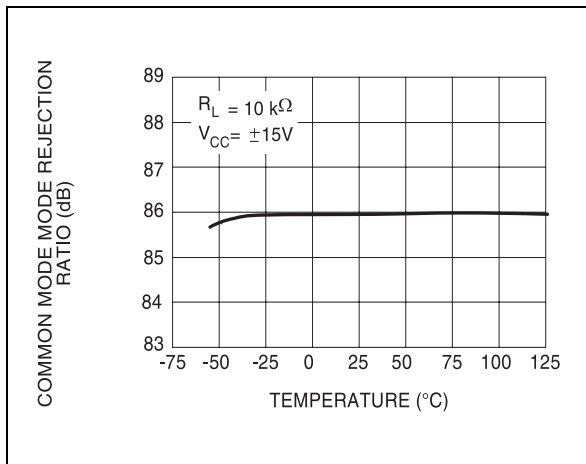


## LARGE SIGNAL DIFFERENTIAL VOLTAGE

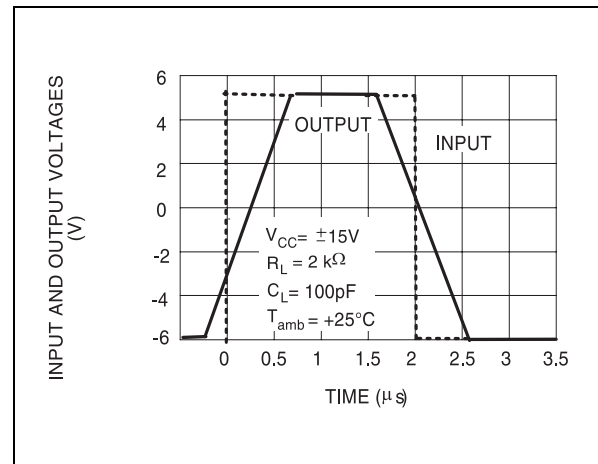


## COMMON MODE REJECTION RATIO versus

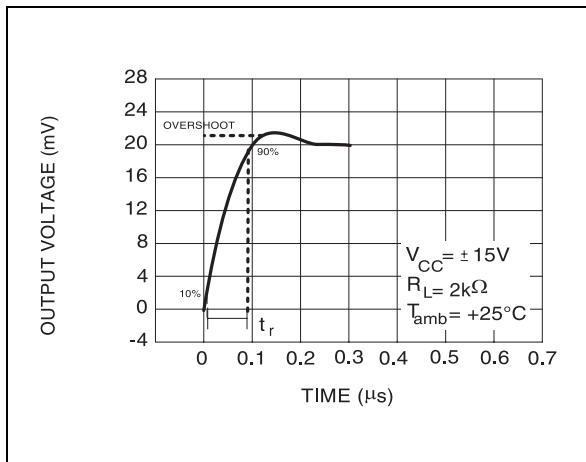
### FREE AIR TEMPERATURE



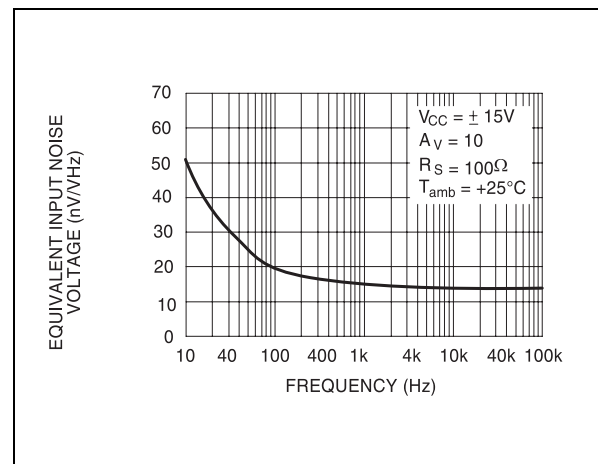
### VOLTAGE FOLLOWER LARGE SIGNAL PULSE RESPONSE



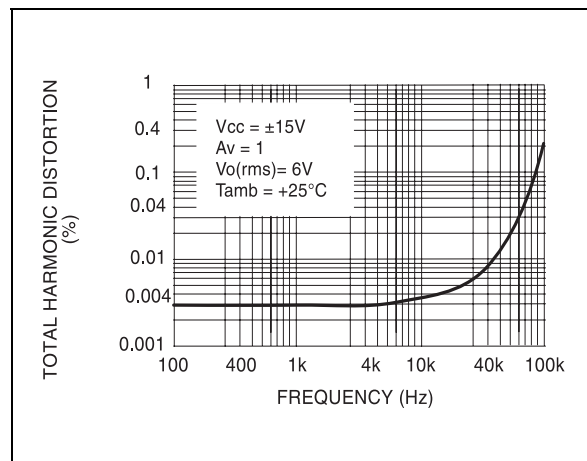
### OUTPUT VOLTAGE versus ELAPSED TIME



### EQUIVALENT INPUT NOISE VOLTAGE versus FREQUENCY

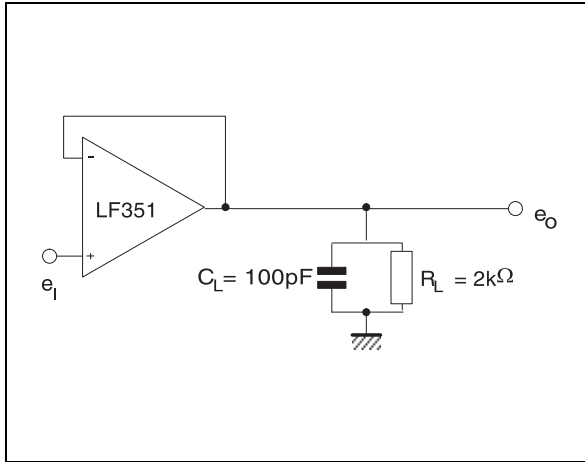


### TOTAL HARMONIC DISTORTION versus FREQUENCY

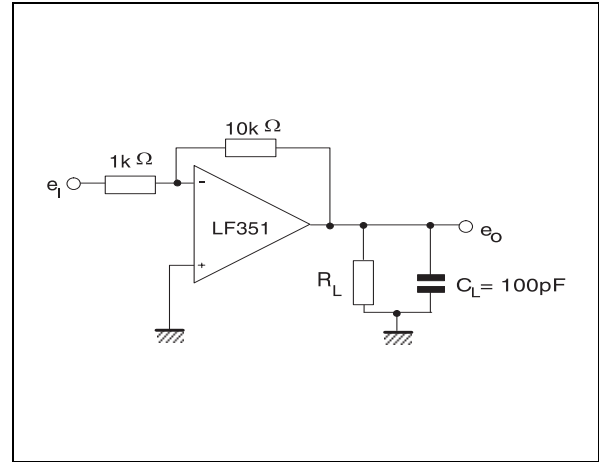


## PARAMETER MEASUREMENT INFORMATION

**Figure 1 : Voltage Follower**

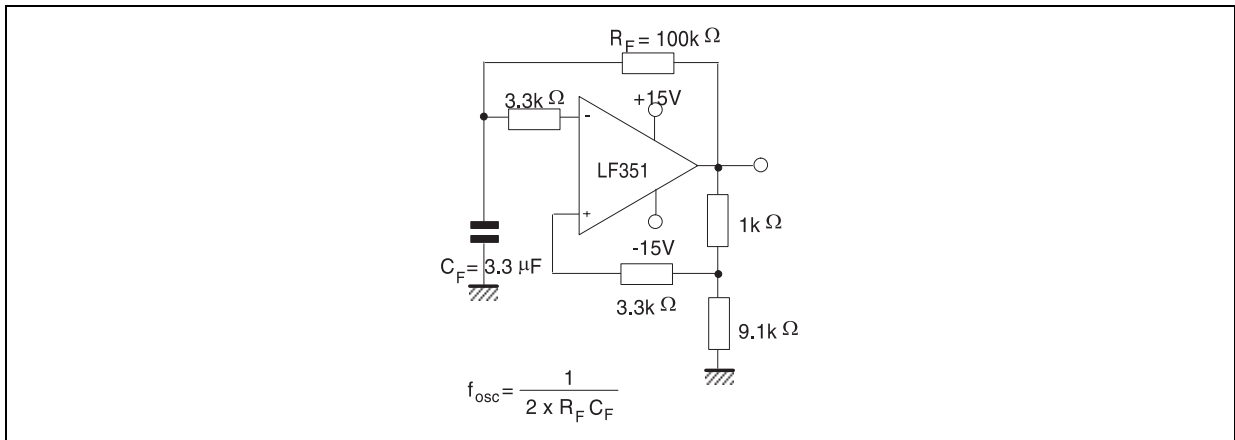


**Figure 2 : Gain-of-10 inverting amplifier**

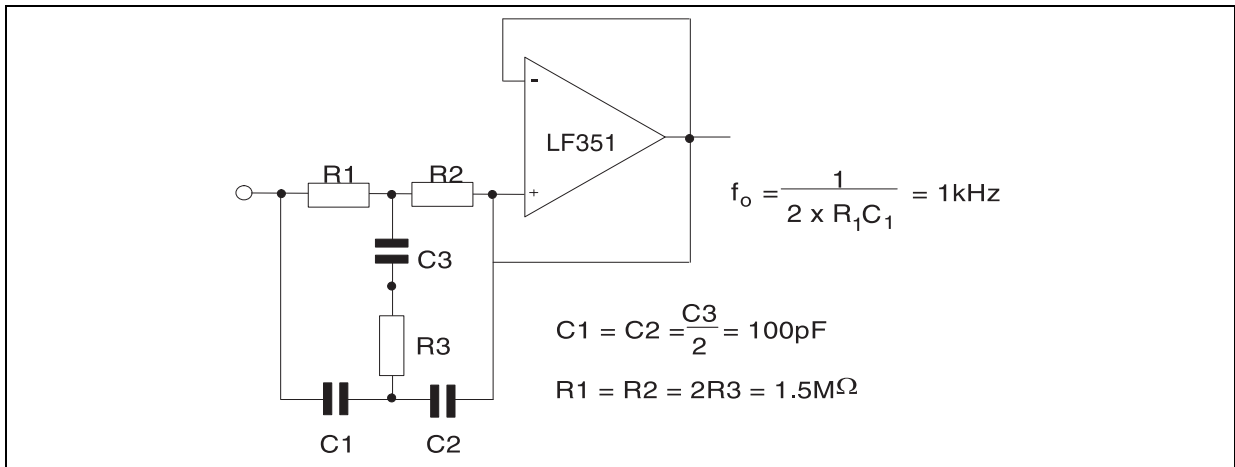


## TYPICAL APPLICATION

### (0.5Hz) SQUARE WAVE OSCILLATOR

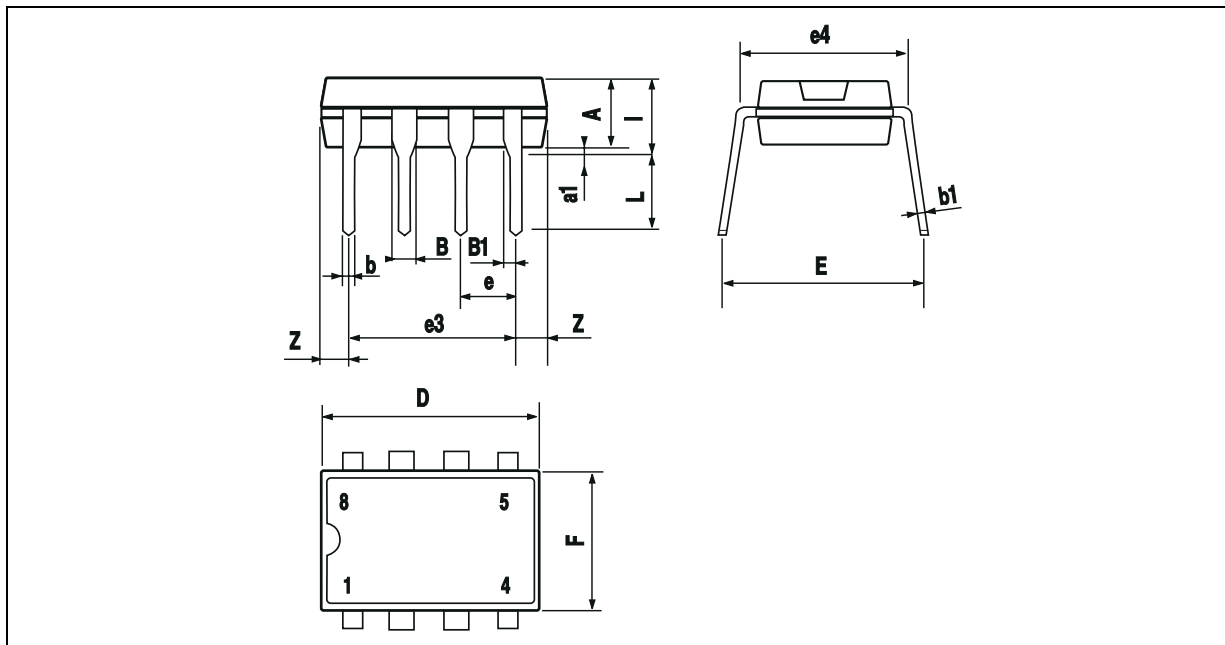


### HIGH Q NOTCH FILTER



**PACKAGE MECHANICAL DATA**

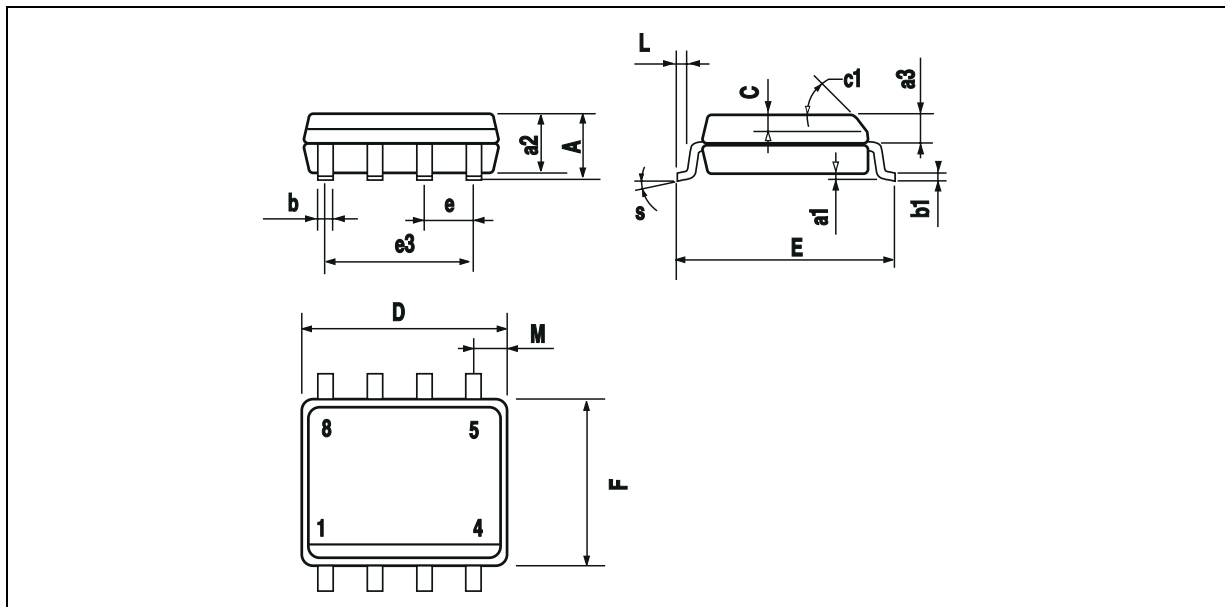
8 PINS - PLASTIC DIP



| Dim. | Millimeters |      |       | Inches |       |       |
|------|-------------|------|-------|--------|-------|-------|
|      | Min.        | Typ. | Max.  | Min.   | Typ.  | Max.  |
| A    |             | 3.32 |       |        | 0.131 |       |
| a1   | 0.51        |      |       | 0.020  |       |       |
| B    | 1.15        |      | 1.65  | 0.045  |       | 0.065 |
| b    | 0.356       |      | 0.55  | 0.014  |       | 0.022 |
| b1   | 0.204       |      | 0.304 | 0.008  |       | 0.012 |
| D    |             |      | 10.92 |        |       | 0.430 |
| E    | 7.95        |      | 9.75  | 0.313  |       | 0.384 |
| e    |             | 2.54 |       |        | 0.100 |       |
| e3   |             | 7.62 |       |        | 0.300 |       |
| e4   |             | 7.62 |       |        | 0.300 |       |
| F    |             |      | 6.6   |        |       | 0.260 |
| i    |             |      | 5.08  |        |       | 0.200 |
| L    | 3.18        |      | 3.81  | 0.125  |       | 0.150 |
| Z    |             |      | 1.52  |        |       | 0.060 |



**PACKAGE MECHANICAL DATA**  
8 PINS - PLASTIC MICROPACKAGE (SO)



| Dim. | Millimeters |      |      | Inches |       |       |
|------|-------------|------|------|--------|-------|-------|
|      | Min.        | Typ. | Max. | Min.   | Typ.  | Max.  |
| A    |             |      | 1.75 |        |       | 0.069 |
| a1   | 0.1         |      | 0.25 | 0.004  |       | 0.010 |
| a2   |             |      | 1.65 |        |       | 0.065 |
| a3   | 0.65        |      | 0.85 | 0.026  |       | 0.033 |
| b    | 0.35        |      | 0.48 | 0.014  |       | 0.019 |
| b1   | 0.19        |      | 0.25 | 0.007  |       | 0.010 |
| C    | 0.25        |      | 0.5  | 0.010  |       | 0.020 |
| c1   | 45° (typ.)  |      |      |        |       |       |
| D    | 4.8         |      | 5.0  | 0.189  |       | 0.197 |
| E    | 5.8         |      | 6.2  | 0.228  |       | 0.244 |
| e    |             | 1.27 |      |        | 0.050 |       |
| e3   |             | 3.81 |      |        | 0.150 |       |
| F    | 3.8         |      | 4.0  | 0.150  |       | 0.157 |
| L    | 0.4         |      | 1.27 | 0.016  |       | 0.050 |
| M    |             |      | 0.6  |        |       | 0.024 |
| S    | 8° (max.)   |      |      |        |       |       |

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